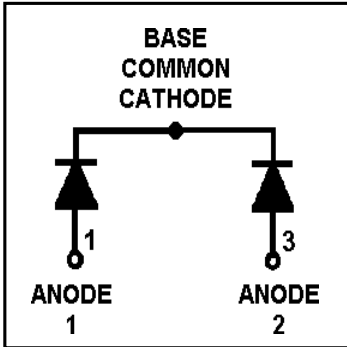


**Features**

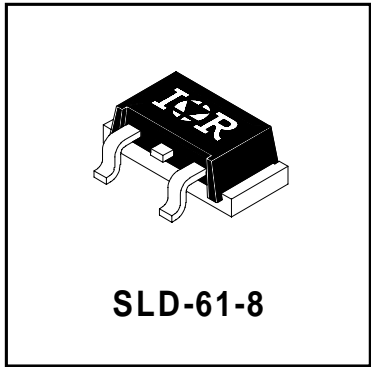
- Reduced RFI and EMI
- Reduced Snubbing
- Extensive Characterization of Recovery Parameters



$V_R = 600V$
$V_F(\text{typ.})^{\textcircled{3}} = 1.2V$
$I_F(\text{AV}) = 70A$
$Q_{rr}(\text{typ.}) = 210nC$
$I_{RRM}(\text{typ.}) = 6A$
$t_{rr}(\text{typ.}) = 30ns$
$di_{(rec)M}/dt(\text{typ.})^{\textcircled{3}} = 180A/\mu s$

**Description**

HEXFRED™ diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and di/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.



**Absolute Maximum Ratings (per Leg)**

	Parameter	Max.	Units
$V_R$	Cathode-to-Anode Voltage	600	V
$I_F @ T_C = 25^\circ C$	Continuous Forward Current	56	A
$I_F @ T_C = 100^\circ C$	Continuous Forward Current	27	
$I_{FSM}$	Single Pulse Forward Current ①	200	
$E_{AS}$	Non-Repetitive Avalanche Energy ②	220	$\mu J$
$P_D @ T_C = 25^\circ C$	Maximum Power Dissipation	150	W
$P_D @ T_C = 100^\circ C$	Maximum Power Dissipation	59	
$T_J$ $T_{STG}$	Operating Junction and Storage Temperature Range	-55 to +150	$^\circ C$
	Soldering Temperature, for 10 sec.	300 (0.063 in. (1.6mm) from case)	

**Thermal - Mechanical Characteristics**

	Parameter	Min.	Typ.	Max.	Units
$R_{thJC}$	Junction-to-Case, Single Leg Conducting	—	—	0.85	$^\circ C/W$
	Junction-to-Case, Both Legs Conducting	—	—	0.42	K/W
Wt	Weight	—	4.3 (0.15)	—	g (oz)

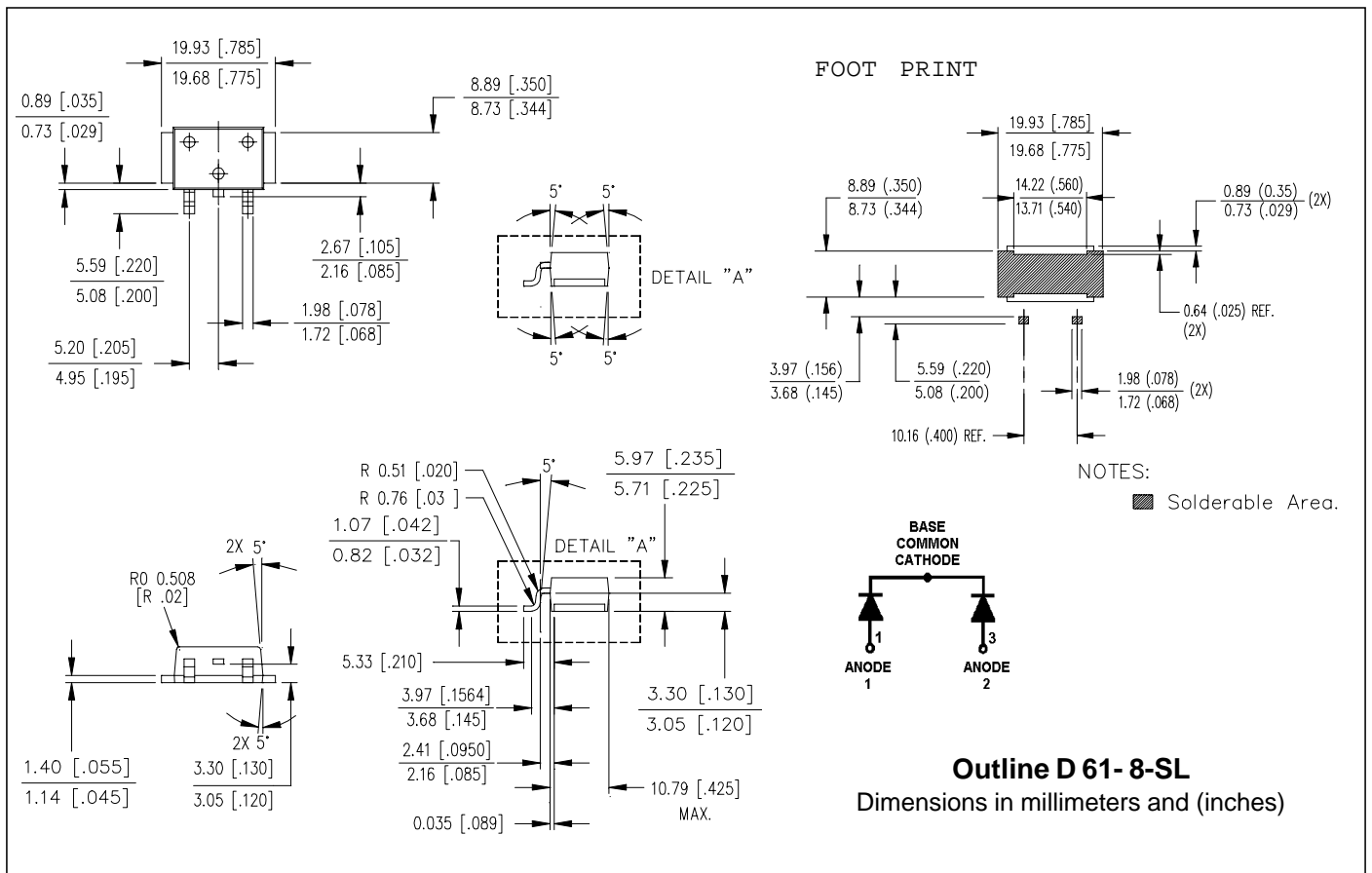
**Note:** ① Limited by junction temperature  
 ② L = 100 $\mu H$ , duty cycle limited by max  $T_J$   
 ③ 125 $^\circ C$

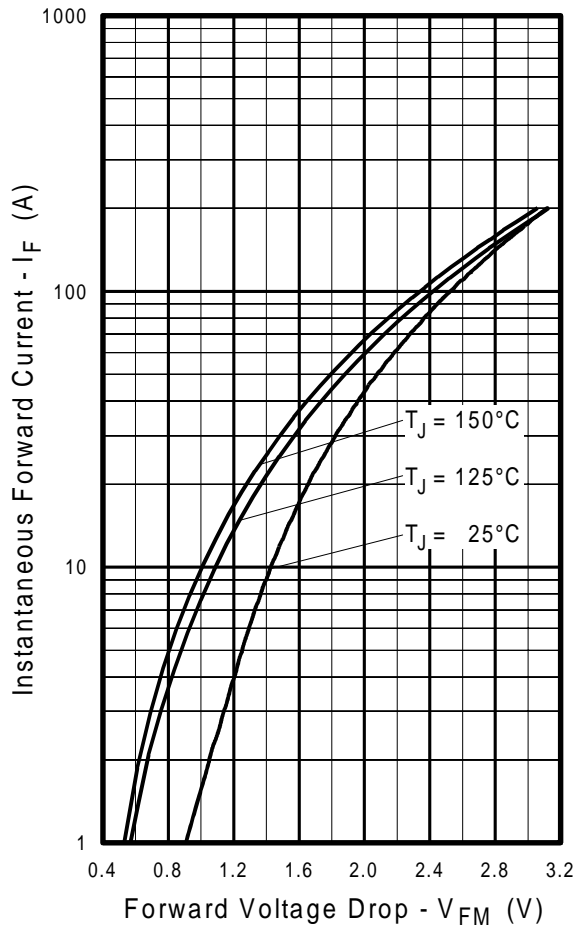
## Electrical Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameter	Min.	Typ.	Max.	Units	Test Conditions
$V_{BR}$	600	—	—	V	$I_R = 100\mu\text{A}$
$V_{FM}$	—	1.3	1.5	V	$I_F = 35\text{A}$ $I_F = 70\text{A}$ See Fig. 1 $I_F = 35\text{A}, T_J = 125^\circ\text{C}$
	—	1.5	1.7		
	—	1.2	1.4		
$I_{RM}$	—	2.0	10	$\mu\text{A}$	$V_R = V_R$ Rated
	—	0.50	2.0	$\text{mA}$	$T_J = 125^\circ\text{C}, V_R = 480\text{V}$ See Fig. 2
$C_T$	—	68	100	$\text{pF}$	$V_R = 200\text{V}$ See Fig. 3
$L_S$	—	5.5	—	$\text{nH}$	Lead to lead 5mm from package body

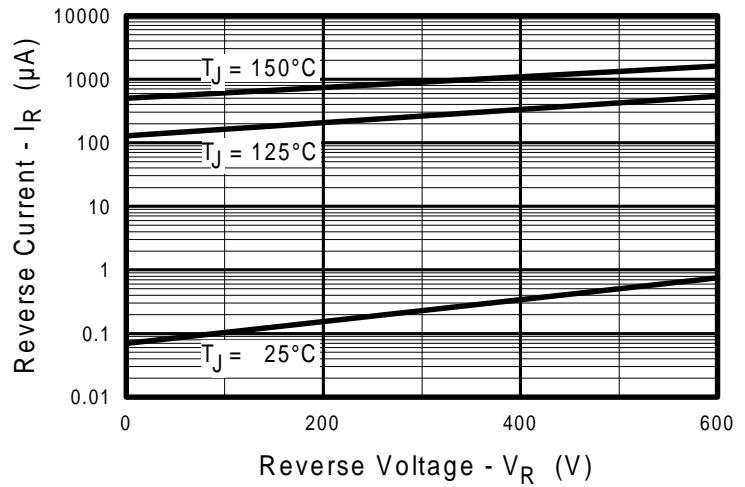
## Dynamic Recovery Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameter	Min.	Typ.	Max.	Units	Test Conditions
$t_{rr}$	—	30	—	ns	$I_F = 1.0\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_R = 30\text{V}$ $T_J = 25^\circ\text{C}$ See Fig. 4 $T_J = 125^\circ\text{C}$ 5
$t_{rr1}$	—	70	110		
$t_{rr2}$	—	115	180		
$I_{RRM1}$	—	6.0	11	A	$T_J = 25^\circ\text{C}$ See Fig. 5
					$T_J = 125^\circ\text{C}$ 6
$I_{RRM2}$	—	9.0	16	A	$T_J = 25^\circ\text{C}$ See Fig. 6
					$T_J = 125^\circ\text{C}$ 7
$Q_{rr1}$	—	210	580	nC	$T_J = 25^\circ\text{C}$ See Fig. 7
					$T_J = 125^\circ\text{C}$ 8
$Q_{rr2}$	—	520	1400	nC	$T_J = 125^\circ\text{C}$ 7
$di_{(rec)M}/dt1$	—	280	—	$\text{A}/\mu\text{s}$	$T_J = 25^\circ\text{C}$ See Fig. 8 $T_J = 125^\circ\text{C}$ 8
$di_{(rec)M}/dt2$	—	180	—		

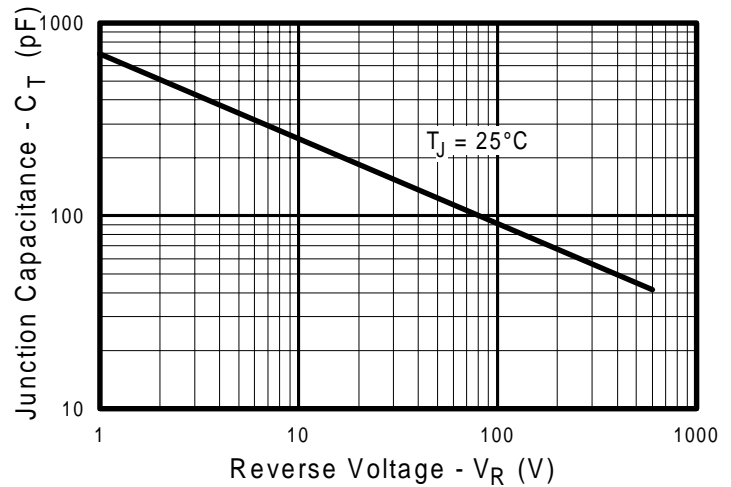




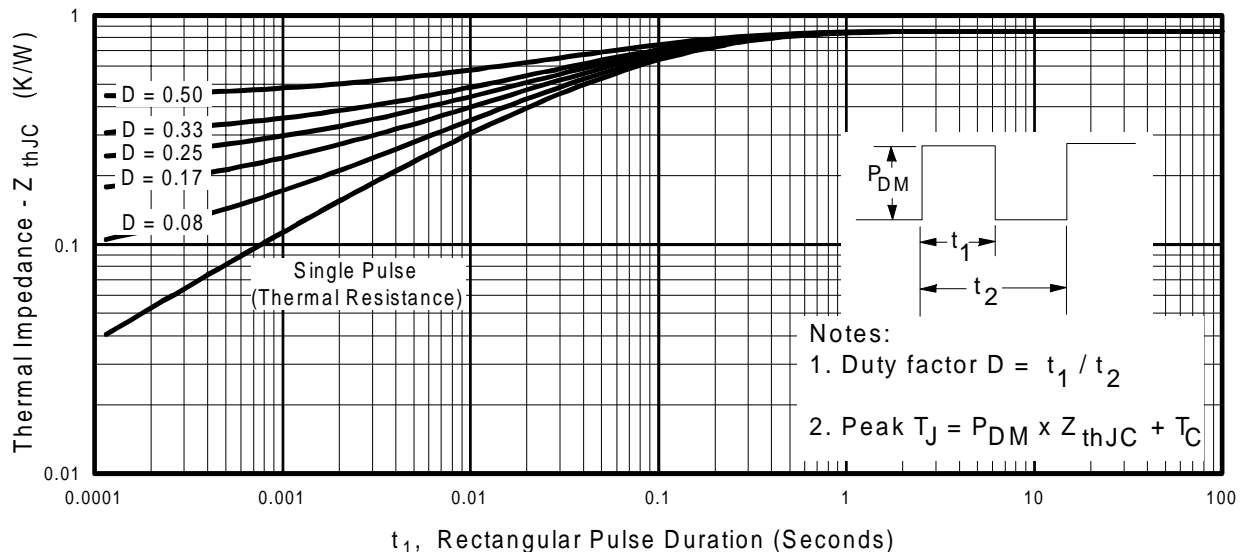
**Fig. 1** - Maximum Forward Voltage Drop vs. Instantaneous Forward Current, (per Leg)



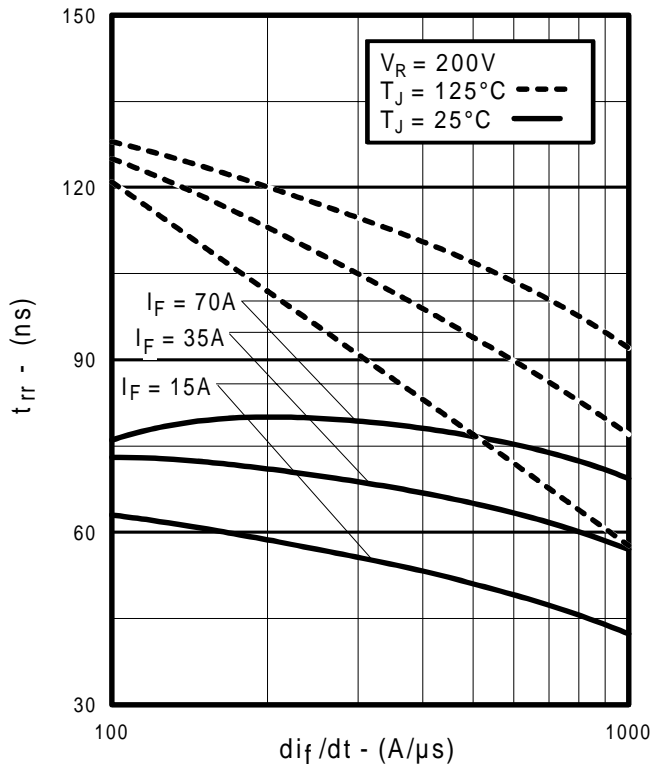
**Fig. 2** - Typical Reverse Current vs. Reverse Voltage, (per Leg)



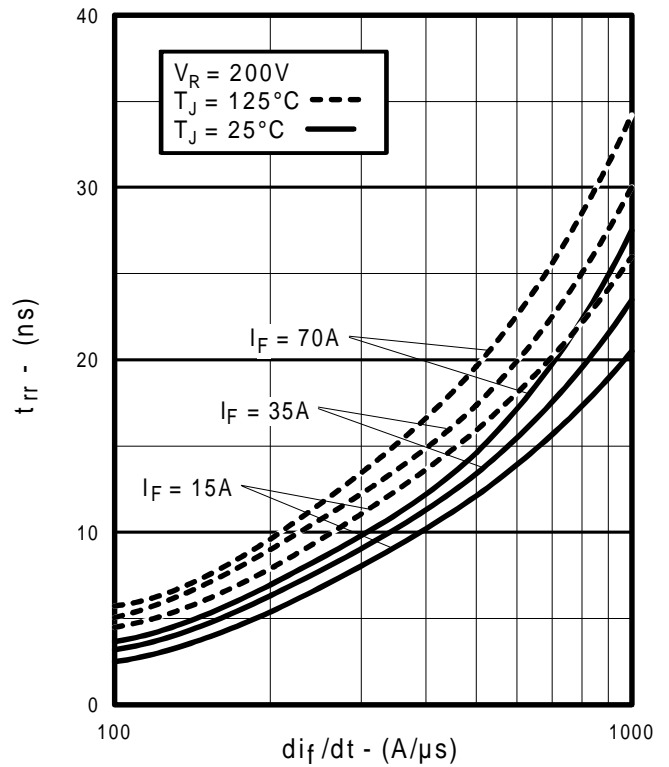
**Fig. 3** - Typical Junction Capacitance vs. Reverse Voltage, (per Leg)



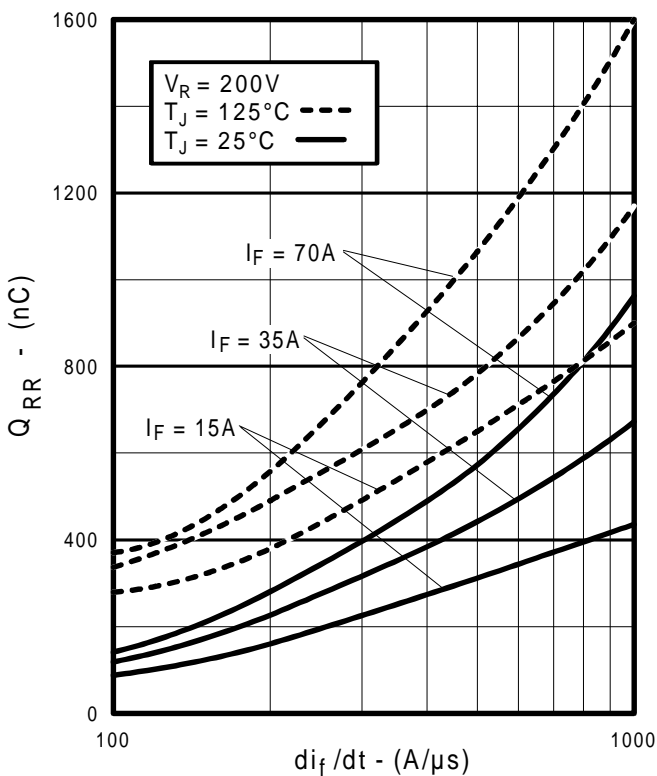
**Fig. 4** - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics, (per Leg)



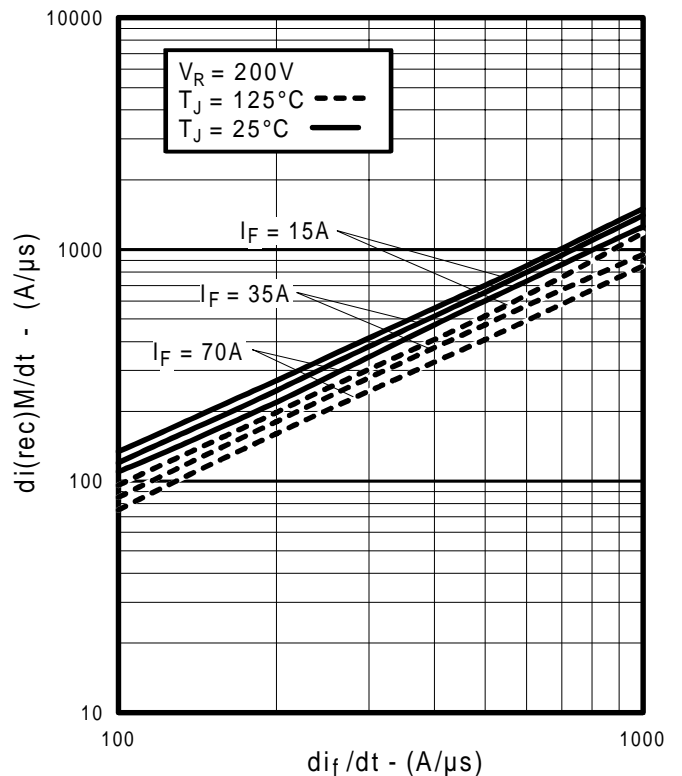
**Fig. 5** - Typical Reverse Recovery vs.  $di_f/dt$ , (per Leg)



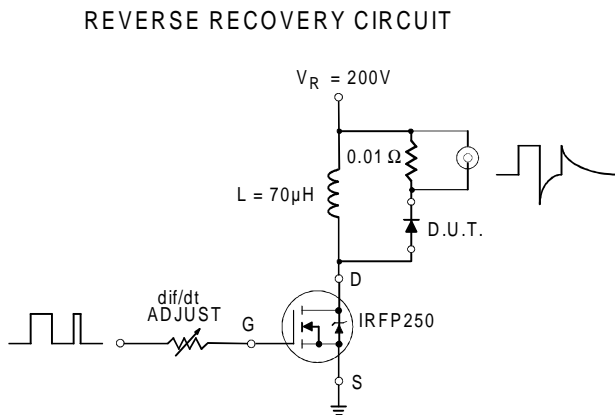
**Fig. 6** - Typical Recovery Current vs.  $di_f/dt$ , (per Leg)



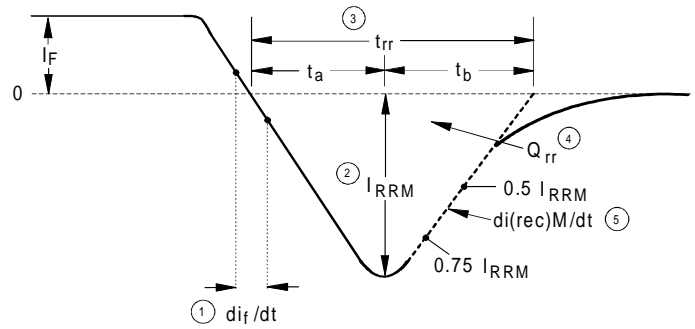
**Fig. 7** - Typical Stored Charge vs.  $di_f/dt$ , (per Leg)



**Fig. 8** - Typical  $di_{(rec)M}/dt$  vs.  $di_f/dt$ , (per Leg)



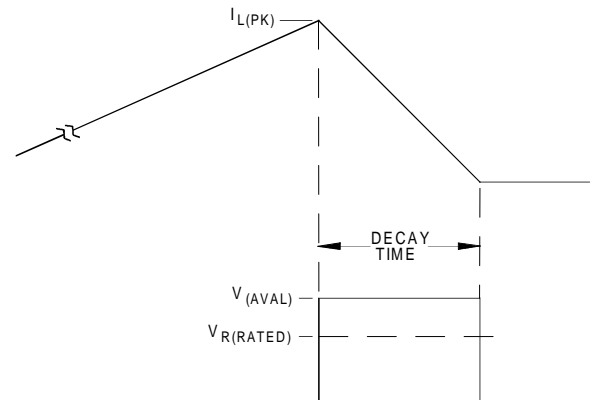
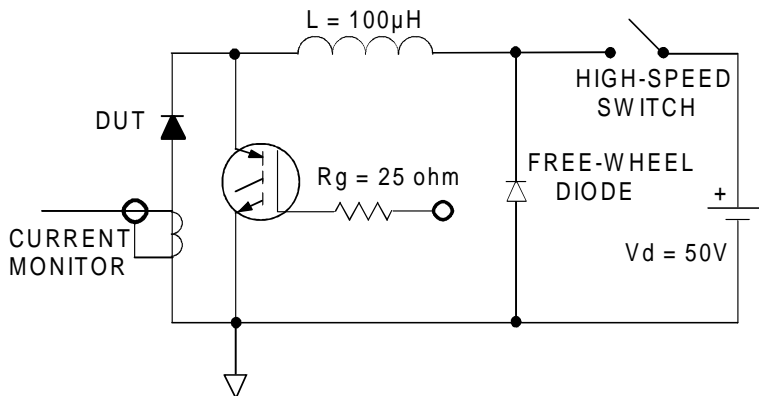
**Fig. 9 - Reverse Recovery Parameter Test Circuit**



1.  $di_f/dt$  - Rate of change of current through zero crossing
2.  $I_{RRM}$  - Peak reverse recovery current
3.  $t_{rr}$  - Reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through  $0.75 I_{RRM}$  and  $0.50 I_{RRM}$  extrapolated to zero current
4.  $Q_{rr}$  - Area under curve defined by  $t_{rr}$  and  $I_{RRM}$
5.  $di_{(rec)M}/dt$  - Peak rate of change of current during  $t_b$  portion of  $t_{rr}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

**Fig. 10 - Reverse Recovery Waveform and Definitions**



**Fig. 11 - Avalanche Test Circuit and Waveforms**